OPB700Z, OPB700ALZ OPB701Z, OPB701ALZ

Features:

- Low profile to facilitate stacking
- Low cost plastic housing
- Choice of phototransistor or photodarlington output
- #26 AWG lead wire in 4" (101 mm), or 18" (457 mm) lengths





Description:

OPB700Z and **OPB700ALZ** sensors consist of an infrared emitting diode and a NPN silicon phototransistor, mounted side-byside on converging optical axes in a black plastic housing.

OPB701Z and **OPB701ALZ** sensors consist of an infrared emitting diode and a NPN silicon photodarlington, mounted side-by -side on converging optical axes in a black plastic housing.

The interconnect wires for these devices are UL approved #26 AWG, with Teflon insulation, stripped and tinned. The **OPB700Z and OPB701Z** have 4" (101 mm) wire length while the **OPB700ALZ and OPB701ALZ** have 18" (457 mm) wire length.

Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor

		Ordering Info	ormation	
Part Number	LED Peak Wavelength	Sensor	Reflection Distance Inch (mm)	Lead Length / Spacing
OPB700Z	890 nm	Transistor		4" / 26 AWG Wire
OPB700ALZ			0.200# (5.08 mm)	18" / 26 AWG Wire
OPB701Z		Darlington	0.200" (5.08 mm)	4" / 26 AWG Wire
OPB701ALZ				18" / 26 AWG Wire



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

Electronics

OPB700Z, OPB700ALZ OPB701Z, OPB701ALZ

OPB700Z, OPB701Z



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OPB700Z, OPB700ALZ OPB701Z, OPB701ALZ

Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Storage Temperature Range	-40° C to + 125° C
Operating Temperature Range	-40° C to + 100° C
Lead Soldering Temperature	260° C
Input Diode	
Continuous Forward Current	100 mA
Reverse Voltage	2 V
Power Dissipation ⁽¹⁾	80 mW
Output Phototransistor	
Collector-Emitter Voltage OPB700Z, OPB700ALZ OPB701Z, OPB701ALZ	24 V 15 V
Emitter-Collector Voltage	5 V
Power Dissipation ⁽¹⁾	50 mW

Notes:

(1) Derate linearly 1.07 mW/° C above 25° C.

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS
Input Diod	e					
V _F	Forward Voltage	-	-	1.7	V	I _F = 50 mA
I _R	Reverse Current	-	-	100	μA	V _R = 2 V
Output Pho	ototransistor					
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage OPB700Z, OPB700ALZ OPB701Z, OPB701ALZ	25 15	-	-	V	I _C = 100 μA
V _{(BR)ECO}	Emitter-Collector Breakdown Voltage	5	-	-	V	I _E = 100 μA
I _{CEO}	Collector Dark Current OPB700Z, OPB700ALZ OPB701Z, OPB701ALZ		-	100 250	nA	$V_{CE} = 10 \text{ V}, \text{ I}_{\text{F}} = 0, \text{ E}_{\text{E}} = \le 0.1 \mu\text{W/cm}^2$

Notes:

(1) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

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OPB700Z, OPB700ALZ OPB701Z, OPB701ALZ



Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	ТҮР	MAX	UNITS	TEST CONDITIONS
Coupled Pa	rameters OPB700Z, OPB700ALZ (Phototra	nsistor)				·
I _{C(ON)}	Collector current	0.10	-	2.50	mA	$V_{CE} = 5.0 V^{(1)}$, $I_F = 40 mA$
V _{CE(SAT)}	Saturation Voltage	-	-	0.40	V	$I_{c} = 10 \ \mu A$, $I_{F} = 40 \ mA$
I _{CX}	Leakage Current	-	-	2.00	μΑ	V_{CE} = 5.0V , I _F = 40 mA, NO Reflective Surface
oupled Pa	rameters OPB701Z, OPB701ALZ (Photodar	lington)				
I _{C(ON)}	Collector current	2.50	-	43.00	mA	$V_{CE} = 5.0 V^{(1)}$, $I_F = 40 mA$
V _{CE(SAT)}	Saturation Voltage	-	-	1.10	V	I _C = 1.0 mA, I _F = 40 mA
I _{CX}	Leakage Current	-	-	20.0	μA	V_{CE} = 5.0 V, I _F = 40 mA, NO Reflective Surface

Notes:

(1) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

Performance



OPB700 - Normalized Collector Current vs Forward Current vs Temperature

Electronics



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Performance



LED—Forward Voltage vs Forward Current vs Temperature



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